

3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC373N	−40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1
74HCT373N				
74HC373D	−40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1
74HCT373D				
74HC373DB	−40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1
74HCT373DB				
74HC373PW	−40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1
74HCT373PW				
74HC373BQ	−40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 × 4.5 × 0.85 mm	SOT764-1
74HCT373BQ				

4. Functional diagram

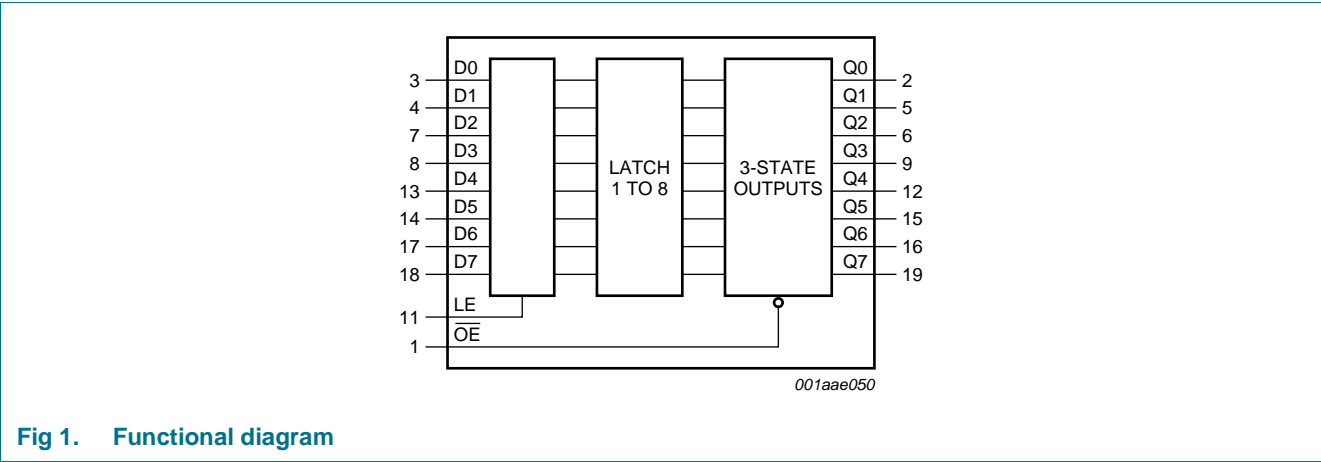


Fig 1. Functional diagram

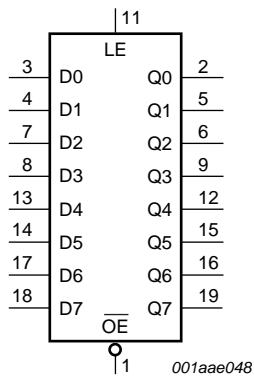


Fig 2. Logic symbol

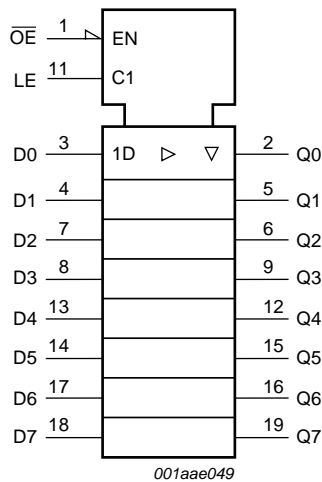


Fig 3. IEC logic symbol

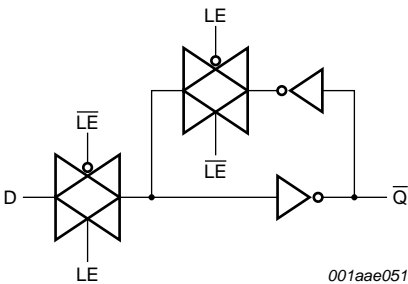


Fig 4. Logic diagram (one latch)

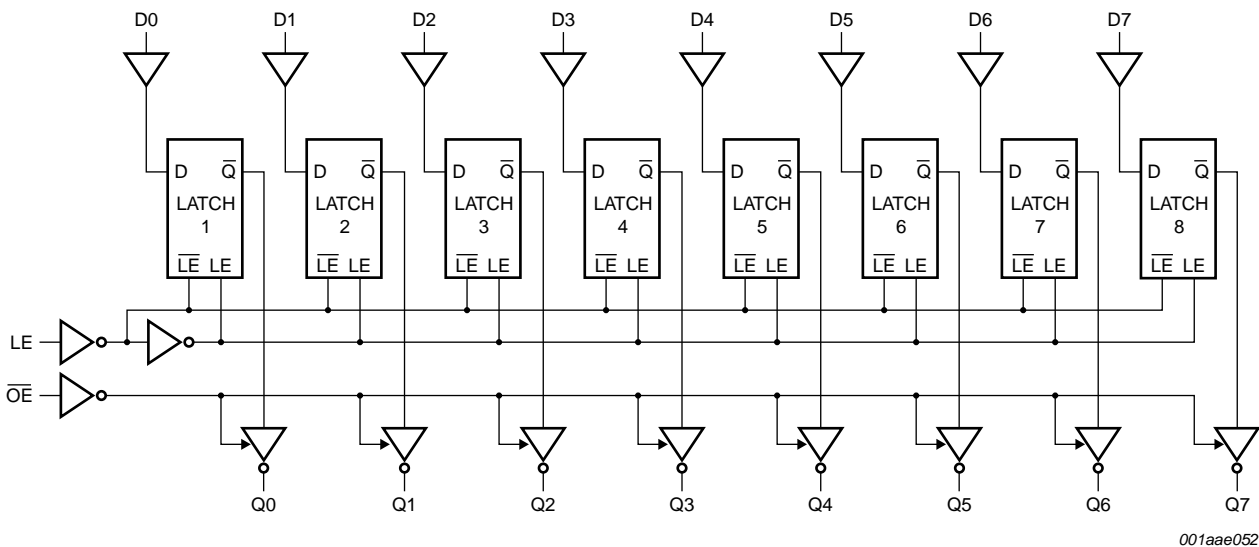
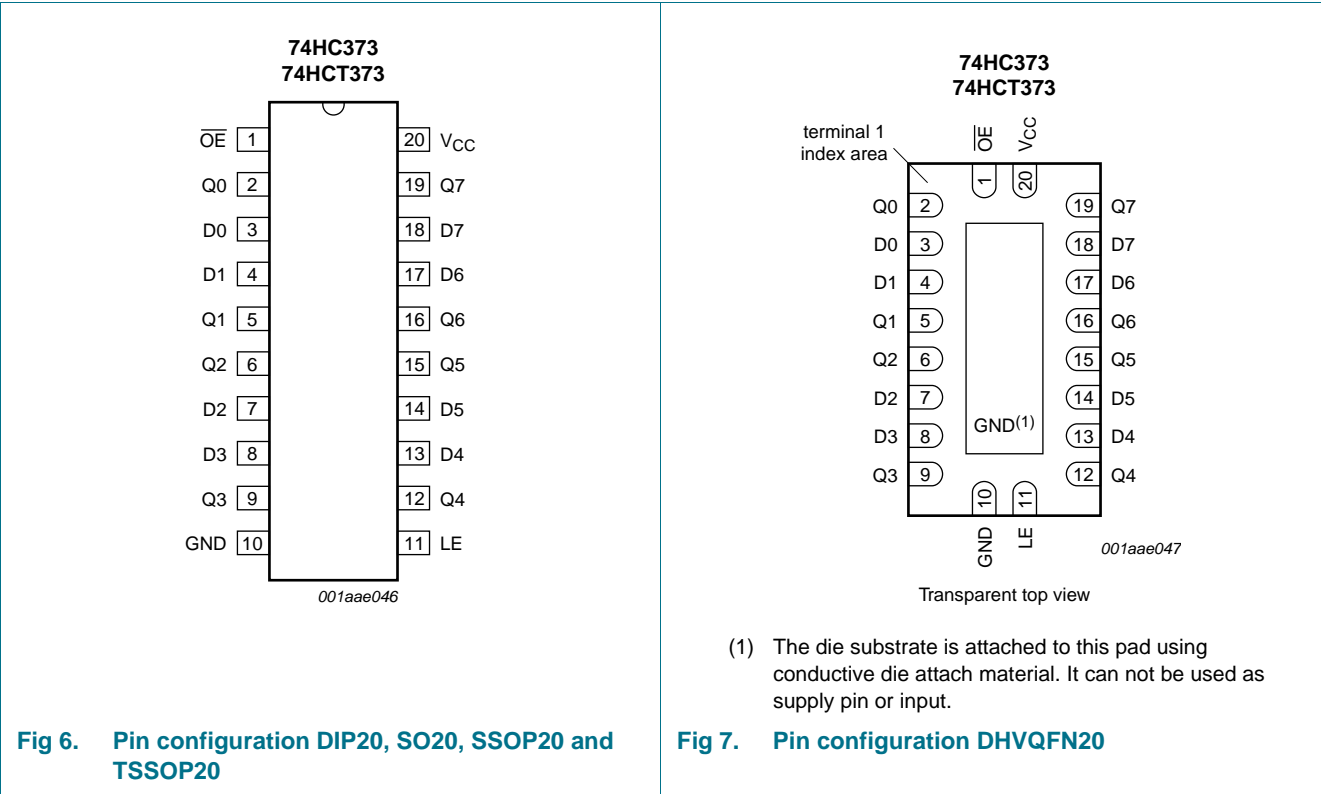


Fig 5. Logic diagram

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
OE	1	3-state output enable input (active LOW)
Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7	2, 5, 6, 9, 12, 15, 16, 19	3-state latch output
D0, D1, D2, D3, D4, D5, D6, D7	3, 4, 7, 8, 13, 14, 17, 18	data input
GND	10	ground (0 V)
LE	11	latch enable input (active HIGH)
VCC	20	supply voltage

## 6. Functional description

### 6.1 Function table

Table 3. Function table<sup>[1]</sup>

Operating mode	Control		Input	Internal latches	Output
	OE	LE	Dn		Qn
Enable and read register (transparent mode)	L	H	L	L	L
			H	H	H
Latch and read register	L	L	l	L	L
			h	H	H
Latch register and disable outputs	H	X	X	X	Z

- [1] H = HIGH voltage level;  
 h = HIGH voltage level one set-up time prior to the HIGH-to-LOW LE transition;  
 L = LOW voltage level;  
 l = LOW voltage level one set-up time prior to the HIGH-to-LOW LE transition;  
 X = don't care;  
 Z = high-impedance OFF-state.

## 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		−0.5	+7	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < −0.5 V or V <sub>I</sub> > V <sub>CC</sub> + 0.5 V	-	±20	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < −0.5 V or V <sub>O</sub> > V <sub>CC</sub> + 0.5 V	-	±20	mA
I <sub>O</sub>	output current	V <sub>O</sub> = −0.5 V to (V <sub>CC</sub> + 0.5 V)	-	±35	mA
I <sub>CC</sub>	supply current		-	+70	mA
I <sub>GND</sub>	ground current		-	−70	mA
T <sub>stg</sub>	storage temperature		−65	+150	°C
P <sub>tot</sub>	total power dissipation	DIP20 package	[1]	-	750 mW
		SO20 package	[2]	-	500 mW
		SSOP20 package	[3]	-	500 mW
		TSSOP20 package	[3]	-	500 mW
		DHVQFN20 package	[4]	-	500 mW

- [1] For DIP20 package: P<sub>tot</sub> derates linearly with 12 mW/K above 70 °C.  
 [2] For SO20: P<sub>tot</sub> derates linearly with 8 mW/K above 70 °C.  
 [3] For SSOP20 and TSSOP20 packages: P<sub>tot</sub> derates linearly with 5.5 mW/K above 60 °C.  
 [4] For DHVQFN20 package: P<sub>tot</sub> derates linearly with 4.5 mW/K above 60 °C.

## 8. Recommended operating conditions

**Table 5. Recommended operating conditions**

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC373			74HCT373			Unit
			Min	Typ	Max	Min	Typ	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
V <sub>I</sub>	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
V <sub>O</sub>	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V

## 9. Static characteristics

**Table 6. Static characteristics 74HC373**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	V
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	V
		V <sub>CC</sub> = 4.5 V	-	2.1	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	-	-	-	
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	V
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	V
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	V
		I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	V
		I <sub>O</sub> = -7.8 mA; V <sub>CC</sub> = 6.0 V	5.48	5.81	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 2.0 V	-	0	0.1	V
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 4.5 V	-	0	0.1	V
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 6.0 V	-	0	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	V
		I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	±0.1	µA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 6.0 V; V <sub>O</sub> = V <sub>CC</sub> or GND	-	-	±0.5	µA
I <sub>CC</sub>	supply current	V <sub>CC</sub> = 6.0 V; I <sub>O</sub> = 0 A; V <sub>I</sub> = V <sub>CC</sub> or GND	-	-	8.0	µA
C <sub>I</sub>	input capacitance		-	3.5	-	pF

**Table 6.** Static characteristics 74HC373 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 2.0 V	1.9	-	-	V
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 6.0 V	5.9	-	-	V
		I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.84	-	-	V
		I <sub>O</sub> = -7.8 mA; V <sub>CC</sub> = 6.0 V	5.34	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 2.0 V	-	-	0.1	V
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 6.0 V	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.33	V
		I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V	-	-	0.33	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	±1.0	µA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 6.0 V; V <sub>O</sub> = V <sub>CC</sub> or GND	-	-	±5.0	µA
I <sub>CC</sub>	supply current	V <sub>CC</sub> = 6.0 V; I <sub>O</sub> = 0 A; V <sub>I</sub> = V <sub>CC</sub> or GND		-	80	µA
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 2.0 V	1.9	-	-	V
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 6.0 V	5.9	-	-	V
		I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.7	-	-	V
		I <sub>O</sub> = -7.8 mA; V <sub>CC</sub> = 6.0 V	5.2	-	-	V

**Table 6.** Static characteristics 74HC373 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 2.0 V	-	-	0.1	V
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 6.0 V	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.4	V
		I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V	-	-	0.4	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	±1.0	µA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 6.0 V; V <sub>O</sub> = V <sub>CC</sub> or GND	-	-	±10.0	µA
I <sub>CC</sub>	supply current	V <sub>CC</sub> = 6.0 V; I <sub>O</sub> = 0 A; V <sub>I</sub> = V <sub>CC</sub> or GND	-	-	160	µA

**Table 7.** Static characteristics 74HCT373

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	V
		I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 4.5 V	-	0.0	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	0.16	0.26	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	±0.1	µA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 5.5 V; V <sub>O</sub> = V <sub>CC</sub> or GND per input pin; other inputs at V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A	-	-	±0.5	µA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	8.0	µA
ΔI <sub>CC</sub>	additional supply current	V <sub>I</sub> = V <sub>CC</sub> - 2.1 V; other inputs at V <sub>CC</sub> or GND; V <sub>CC</sub> = 4.5 V to 5.5 V; I <sub>O</sub> = 0 A				
		Dn	-	30	108	µA
		LE	-	150	540	µA
		$\overline{\text{OE}}$	-	100	360	µA
C <sub>I</sub>	input capacitance		-	3.5	-	pF
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V

**Table 7. Static characteristics 74HCT373 ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = −20 μA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = −6.0 μA; V <sub>CC</sub> = 4.5 V	3.84	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.33	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	±1.0	μA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 5.5 V; V <sub>O</sub> = V <sub>CC</sub> or GND per input pin; other inputs at V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A	-	-	±5.0	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	80	μA
ΔI <sub>CC</sub>	additional supply current	V <sub>I</sub> = V <sub>CC</sub> − 2.1 V; other inputs at V <sub>CC</sub> or GND; V <sub>CC</sub> = 4.5 V to 5.5 V; I <sub>O</sub> = 0 A				
		Dn	-	-	135	μA
		LE	-	-	675	μA
		$\overline{\text{OE}}$	-	-	450	μA
T <sub>amb</sub> = −40 °C to +125 °C						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = −20 μA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = −6.0 mA; V <sub>CC</sub> = 4.5 V	3.7	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.4	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	±1.0	μA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 5.5 V; V <sub>O</sub> = V <sub>CC</sub> or GND per input pin; other inputs at V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A	-	-	±10	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	160	μA
ΔI <sub>CC</sub>	additional supply current	V <sub>I</sub> = V <sub>CC</sub> − 2.1 V; other inputs at V <sub>CC</sub> or GND; V <sub>CC</sub> = 4.5 V to 5.5 V; I <sub>O</sub> = 0 A				
		Dn	-	-	147	μA
		LE	-	-	735	μA
		$\overline{\text{OE}}$	-	-	490	μA



## 10. Dynamic characteristics

**Table 8. Dynamic characteristics 74HC373**

Voltages are referenced to GND (ground = 0 V);  $C_L = 50$  pF unless otherwise specified; for test circuit see [Figure 12](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
t <sub>pd</sub>	propagation delay	Dn to Qn; see <a href="#">Figure 8</a>	[1]			
		V <sub>CC</sub> = 2.0 V	-	41	150	ns
		V <sub>CC</sub> = 4.5 V	-	15	30	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	12	-	ns
		V <sub>CC</sub> = 6.0 V	-	12	26	ns
		LE to Qn; see <a href="#">Figure 9</a>				
		V <sub>CC</sub> = 2.0 V	-	50	175	ns
		V <sub>CC</sub> = 4.5 V	-	18	35	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	15	-	ns
		V <sub>CC</sub> = 6.0 V	-	14	30	ns
t <sub>en</sub>	enable time	OE to Qn; see <a href="#">Figure 10</a>	[2]			
		V <sub>CC</sub> = 2.0 V	-	44	150	ns
		V <sub>CC</sub> = 4.5 V	-	16	30	ns
		V <sub>CC</sub> = 6.0 V	-	13	26	ns
t <sub>dis</sub>	disable time	OE to Qn; see <a href="#">Figure 10</a>	[3]			
		V <sub>CC</sub> = 2.0 V	-	47	150	ns
		V <sub>CC</sub> = 4.5 V	-	17	30	ns
		V <sub>CC</sub> = 6.0 V	-	14	26	ns
t <sub>t</sub>	transition time	Qn; see <a href="#">Figure 8</a> and <a href="#">Figure 9</a>	[4]			
		V <sub>CC</sub> = 2.0 V	-	14	60	ns
		V <sub>CC</sub> = 4.5 V	-	5	12	ns
		V <sub>CC</sub> = 6.0 V	-	4	10	ns
t <sub>w</sub>	pulse width	LE HIGH; see <a href="#">Figure 9</a>				
		V <sub>CC</sub> = 2.0 V	80	17	-	ns
		V <sub>CC</sub> = 4.5 V	16	6	-	ns
		V <sub>CC</sub> = 6.0 V	14	5	-	ns
t <sub>su</sub>	set-up time	Dn to LE; see <a href="#">Figure 11</a>				
		V <sub>CC</sub> = 2.0 V	50	14	-	ns
		V <sub>CC</sub> = 4.5 V	10	5	-	ns
		V <sub>CC</sub> = 6.0 V	9	4	-	ns
t <sub>h</sub>	hold time	Dn to LE; see <a href="#">Figure 11</a>				
		V <sub>CC</sub> = 2.0 V	+5	-8	-	ns
		V <sub>CC</sub> = 4.5 V	+5	-3	-	ns
		V <sub>CC</sub> = 6.0 V	+5	-2	-	ns
C <sub>PD</sub>	power dissipation capacitance	per latch; V <sub>I</sub> = GND to V <sub>CC</sub>	[5]	-	45	pF

**Table 8. Dynamic characteristics 74HC373 ...continued**

Voltages are referenced to GND (ground = 0 V);  $C_L = 50$  pF unless otherwise specified; for test circuit see [Figure 12](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{amb} = -40\text{ °C to }+85\text{ °C}$						
$t_{pd}$	propagation delay	Dn to Qn; see <a href="#">Figure 8</a>	<a href="#">[1]</a>			
		$V_{CC} = 2.0\text{ V}$	-	-	190	ns
		$V_{CC} = 4.5\text{ V}$	-	-	38	ns
		$V_{CC} = 6.0\text{ V}$	-	-	33	ns
		LE to Qn; see <a href="#">Figure 9</a>				
		$V_{CC} = 2.0\text{ V}$	-	-	220	ns
		$V_{CC} = 4.5\text{ V}$	-	-	44	ns
		$V_{CC} = 6.0\text{ V}$	-	-	37	ns
$t_{en}$	enable time	$\overline{OE}$ to Qn; see <a href="#">Figure 10</a>	<a href="#">[2]</a>			
		$V_{CC} = 2.0\text{ V}$	-	-	190	ns
		$V_{CC} = 4.5\text{ V}$	-	-	38	ns
		$V_{CC} = 6.0\text{ V}$	-	-	33	ns
$t_{dis}$	disable time	$\overline{OE}$ to Qn; see <a href="#">Figure 10</a>	<a href="#">[3]</a>			
		$V_{CC} = 2.0\text{ V}$	-	-	190	ns
		$V_{CC} = 4.5\text{ V}$	-	-	38	ns
		$V_{CC} = 6.0\text{ V}$	-	-	33	ns
$t_t$	transition time	Qn; see <a href="#">Figure 8</a> and <a href="#">Figure 9</a>	<a href="#">[4]</a>			
		$V_{CC} = 2.0\text{ V}$	-	-	75	ns
		$V_{CC} = 4.5\text{ V}$	-	-	15	ns
		$V_{CC} = 6.0\text{ V}$	-	-	13	ns
$t_W$	pulse width	LE HIGH; see <a href="#">Figure 9</a>				
		$V_{CC} = 2.0\text{ V}$	100	-	-	ns
		$V_{CC} = 4.5\text{ V}$	20	-	-	ns
		$V_{CC} = 6.0\text{ V}$	17	-	-	ns
$t_{su}$	set-up time	Dn to LE; see <a href="#">Figure 11</a>				
		$V_{CC} = 2.0\text{ V}$	65	-	-	ns
		$V_{CC} = 4.5\text{ V}$	13	-	-	ns
		$V_{CC} = 6.0\text{ V}$	11	-	-	ns
$t_h$	hold time	Dn to LE; see <a href="#">Figure 11</a>				
		$V_{CC} = 2.0\text{ V}$	5	-	-	ns
		$V_{CC} = 4.5\text{ V}$	5	-	-	ns
		$V_{CC} = 6.0\text{ V}$	5	-	-	ns

**Table 8. Dynamic characteristics 74HC373 ...continued**

Voltages are referenced to GND (ground = 0 V);  $C_L = 50$  pF unless otherwise specified; for test circuit see [Figure 12](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = -40\text{ °C to }+125\text{ °C}</math></b>						
$t_{pd}$	propagation delay	Dn to Qn; see <a href="#">Figure 8</a>	<a href="#">[1]</a>			
		$V_{CC} = 2.0\text{ V}$	-	-	225	ns
		$V_{CC} = 4.5\text{ V}$	-	-	45	ns
		$V_{CC} = 6.0\text{ V}$	-	-	38	ns
		LE to Qn; see <a href="#">Figure 9</a>				
		$V_{CC} = 2.0\text{ V}$	-	-	265	ns
		$V_{CC} = 4.5\text{ V}$	-	-	53	ns
		$V_{CC} = 6.0\text{ V}$	-	-	45	ns
$t_{en}$	enable time	$\overline{OE}$ to Qn; see <a href="#">Figure 10</a>	<a href="#">[2]</a>			
		$V_{CC} = 2.0\text{ V}$	-	-	225	ns
		$V_{CC} = 4.5\text{ V}$	-	-	45	ns
		$V_{CC} = 6.0\text{ V}$	-	-	38	ns
$t_{dis}$	disable time	$\overline{OE}$ to Qn; see <a href="#">Figure 10</a>	<a href="#">[3]</a>			
		$V_{CC} = 2.0\text{ V}$	-	-	225	ns
		$V_{CC} = 4.5\text{ V}$	-	-	45	ns
		$V_{CC} = 6.0\text{ V}$	-	-	38	ns
$t_t$	transition time	Qn; see <a href="#">Figure 8</a> and <a href="#">Figure 9</a>	<a href="#">[4]</a>			
		$V_{CC} = 2.0\text{ V}$	-	-	90	ns
		$V_{CC} = 4.5\text{ V}$	-	-	18	ns
		$V_{CC} = 6.0\text{ V}$	-	-	15	ns
$t_W$	pulse width	LE HIGH; see <a href="#">Figure 9</a>				
		$V_{CC} = 2.0\text{ V}$	120	-	-	ns
		$V_{CC} = 4.5\text{ V}$	24	-	-	ns
		$V_{CC} = 6.0\text{ V}$	20	-	-	ns
$t_{su}$	set-up time	Dn to LE; see <a href="#">Figure 11</a>				
		$V_{CC} = 2.0\text{ V}$	75	-	-	ns
		$V_{CC} = 4.5\text{ V}$	15	-	-	ns
		$V_{CC} = 6.0\text{ V}$	13	-	-	ns

**Table 8. Dynamic characteristics 74HC373 ...continued**

Voltages are referenced to GND (ground = 0 V);  $C_L = 50$  pF unless otherwise specified; for test circuit see [Figure 12](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_h$	hold time	Dn to LE; see <a href="#">Figure 11</a>				
		$V_{CC} = 2.0$ V	5	-	-	ns
		$V_{CC} = 4.5$ V	5	-	-	ns
		$V_{CC} = 6.0$ V	5	-	-	ns

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[2]  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .

[3]  $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .

[4]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

[5]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

**Table 9. Dynamic characteristics 74HCT373**

Voltages are referenced to GND (ground = 0 V);  $C_L = 50$  pF unless otherwise specified; for test circuit see [Figure 12](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = 25</math> °C</b>						
$t_{pd}$	propagation delay	Dn to Qn; see <a href="#">Figure 8</a>	[1]			
		$V_{CC} = 4.5$ V	-	17	30	ns
		$V_{CC} = 5$ V; $C_L = 15$ pF	-	14	-	ns
		LE to Qn; see <a href="#">Figure 9</a>				
		$V_{CC} = 4.5$ V	-	16	32	ns
		$V_{CC} = 5$ V; $C_L = 15$ pF	-	13	-	ns
$t_{en}$	enable time	$\overline{OE}$ to Qn; see <a href="#">Figure 10</a>	[2]			
		$V_{CC} = 4.5$ V	-	19	32	ns
$t_{dis}$	disable time	$\overline{OE}$ to Qn; see <a href="#">Figure 10</a>	[3]			
		$V_{CC} = 4.5$ V	-	18	30	ns
$t_t$	transition time	Qn; see <a href="#">Figure 8</a> and <a href="#">Figure 9</a>	[4]			
		$V_{CC} = 4.5$ V	-	5	12	ns
$t_W$	pulse width	LE HIGH; see <a href="#">Figure 9</a>				
		$V_{CC} = 4.5$ V	16	4	-	ns
$t_{su}$	set-up time	Dn to LE; see <a href="#">Figure 11</a>				
		$V_{CC} = 4.5$ V	12	6	-	ns
$t_h$	hold time	Dn to LE; see <a href="#">Figure 11</a>				
		$V_{CC} = 4.5$ V	4	-1	-	ns
$C_{PD}$	power dissipation capacitance	per latch; $V_I = \text{GND to } (V_{CC} - 1.5 \text{ V})$	[5]	-	41	pF

**Table 9. Dynamic characteristics 74HCT373 ...continued**

Voltages are referenced to GND (ground = 0 V);  $C_L = 50$  pF unless otherwise specified; for test circuit see [Figure 12](#).

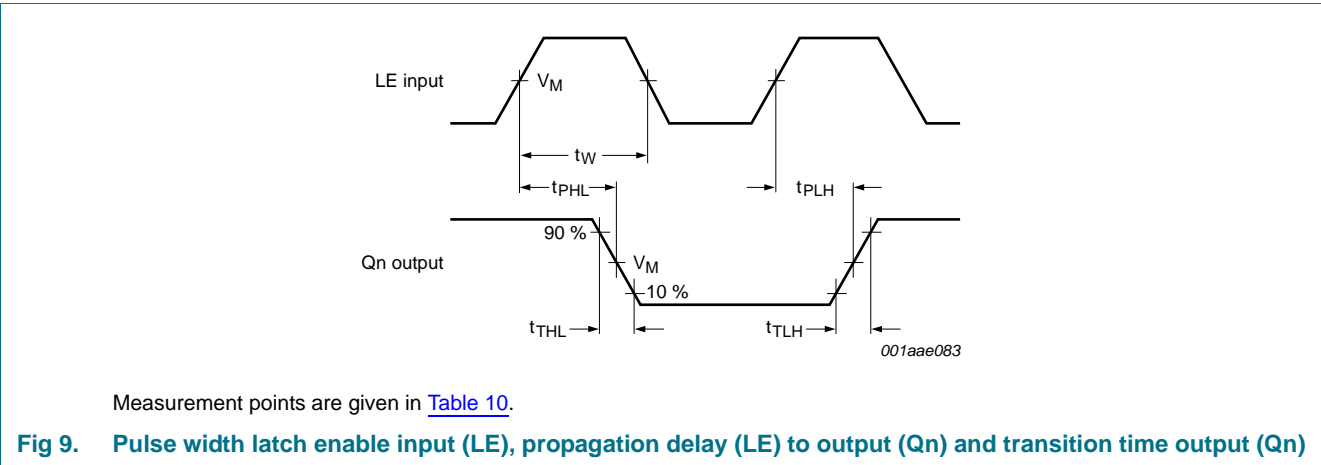
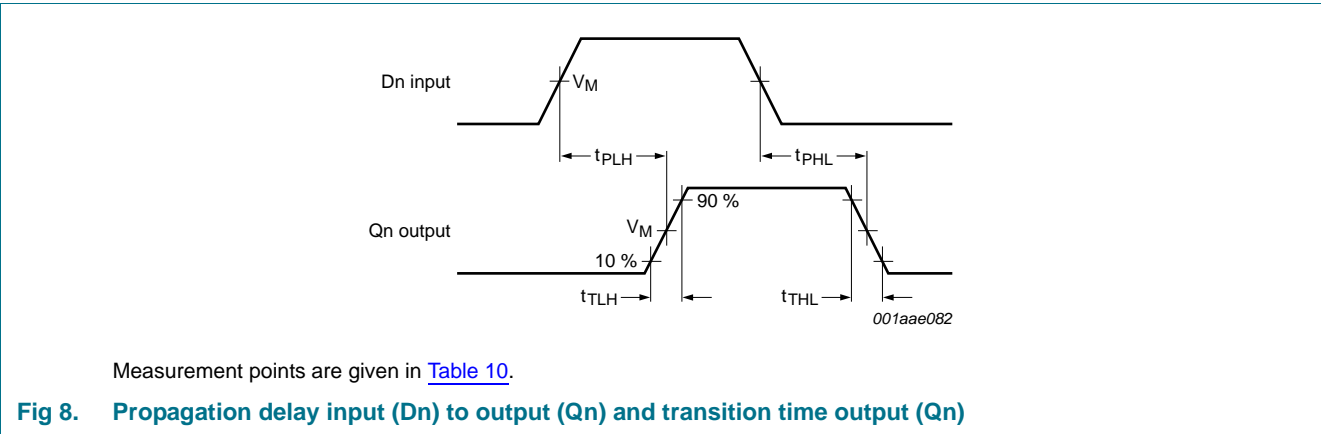
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = -40\text{ °C to }+85\text{ °C}</math></b>						
$t_{pd}$	propagation delay	Dn to Qn; see <a href="#">Figure 8</a>	[1]			
		$V_{CC} = 4.5\text{ V}$	-	-	38	ns
		LE to Qn; see <a href="#">Figure 9</a>				
		$V_{CC} = 4.5\text{ V}$	-	-	40	ns
$t_{en}$	enable time	$\overline{OE}$ to Qn; see <a href="#">Figure 10</a>	[2]			
		$V_{CC} = 4.5\text{ V}$	-	-	40	ns
$t_{dis}$	disable time	$\overline{OE}$ to Qn; see <a href="#">Figure 10</a>	[3]			
		$V_{CC} = 4.5\text{ V}$	-	-	38	ns
$t_t$	transition time	Qn; see <a href="#">Figure 8</a> and <a href="#">Figure 9</a>	[4]			
		$V_{CC} = 4.5\text{ V}$	-	-	15	ns
$t_W$	pulse width	LE HIGH; see <a href="#">Figure 9</a>				
		$V_{CC} = 4.5\text{ V}$	20	-	-	ns
$t_{su}$	set-up time	Dn to LE; see <a href="#">Figure 11</a>				
		$V_{CC} = 4.5\text{ V}$	15	-	-	ns
$t_h$	hold time	Dn to LE; see <a href="#">Figure 11</a>				
		$V_{CC} = 4.5\text{ V}$	4	-	-	ns
<b><math>T_{amb} = -40\text{ °C to }+125\text{ °C}</math></b>						
$t_{pd}$	propagation delay	Dn to Qn; see <a href="#">Figure 8</a>	[1]			
		$V_{CC} = 4.5\text{ V}$	-	-	45	ns
		LE to Qn; see <a href="#">Figure 9</a>				
		$V_{CC} = 4.5\text{ V}$	-	-	48	ns
$t_{en}$	enable time	$\overline{OE}$ to Qn; see <a href="#">Figure 10</a>	[2]			
		$V_{CC} = 4.5\text{ V}$	-	-	48	ns
$t_{dis}$	disable time	$\overline{OE}$ to Qn; see <a href="#">Figure 10</a>	[3]			
		$V_{CC} = 4.5\text{ V}$	-	-	45	ns
$t_t$	transition time	Qn; see <a href="#">Figure 8</a> and <a href="#">Figure 9</a>	[4]			
		$V_{CC} = 4.5\text{ V}$	-	-	18	ns
$t_W$	pulse width	LE HIGH; see <a href="#">Figure 9</a>				
		$V_{CC} = 4.5\text{ V}$	24	-	-	ns
$t_{su}$	set-up time Dn to LE	Dn to LE; see <a href="#">Figure 11</a>				
		$V_{CC} = 4.5\text{ V}$	18	-	-	ns

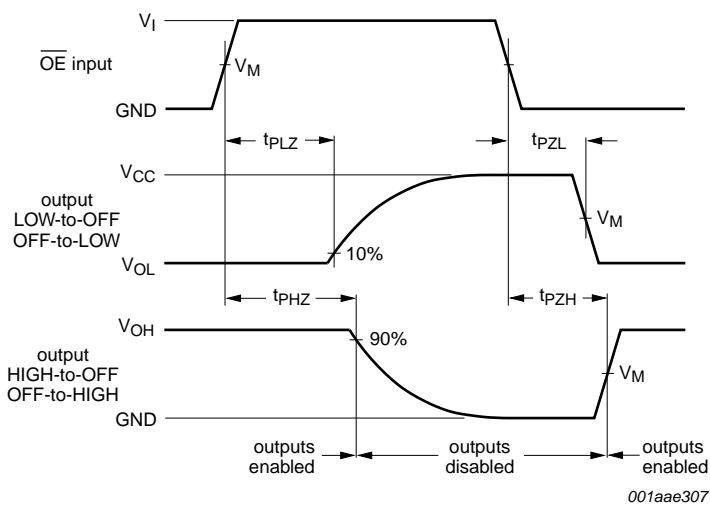
**Table 9. Dynamic characteristics 74HCT373 ...continued**  
Voltages are referenced to GND (ground = 0 V);  $C_L = 50\text{ pF}$  unless otherwise specified; for test circuit see [Figure 12](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_h$	hold time Dn to LE	Dn to LE; see <a href="#">Figure 11</a> $V_{CC} = 4.5\text{ V}$	4	-	-	ns

- [1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .  
[2]  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .  
[3]  $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .  
[4]  $t_i$  is the same as  $t_{THL}$  and  $t_{TLH}$ .  
[5]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o)$  where:  
 $f_i$  = input frequency in MHz;  
 $f_o$  = output frequency in MHz;  
 $C_L$  = output load capacitance in pF;  
 $V_{CC}$  = supply voltage in V;  
 $N$  = number of inputs switching;  
 $\sum(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

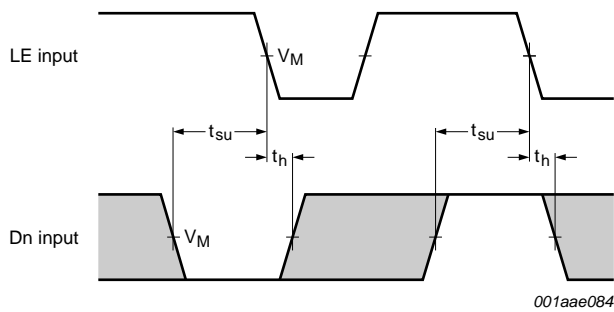
11. Waveforms





Measurement points are given in [Table 10](#).

Fig 10. 3-state enable and disable time



Measurement points are given in [Table 10](#).

Fig 11. Set-up and hold time data input (Dn) to latch enable input (LE)

Table 10. Measurement points

Type	Input	Output
	$V_M$	$V_M$
74HC373	$0.5V_{CC}$	$0.5V_{CC}$
74HCT373	1.3 V	1.3 V

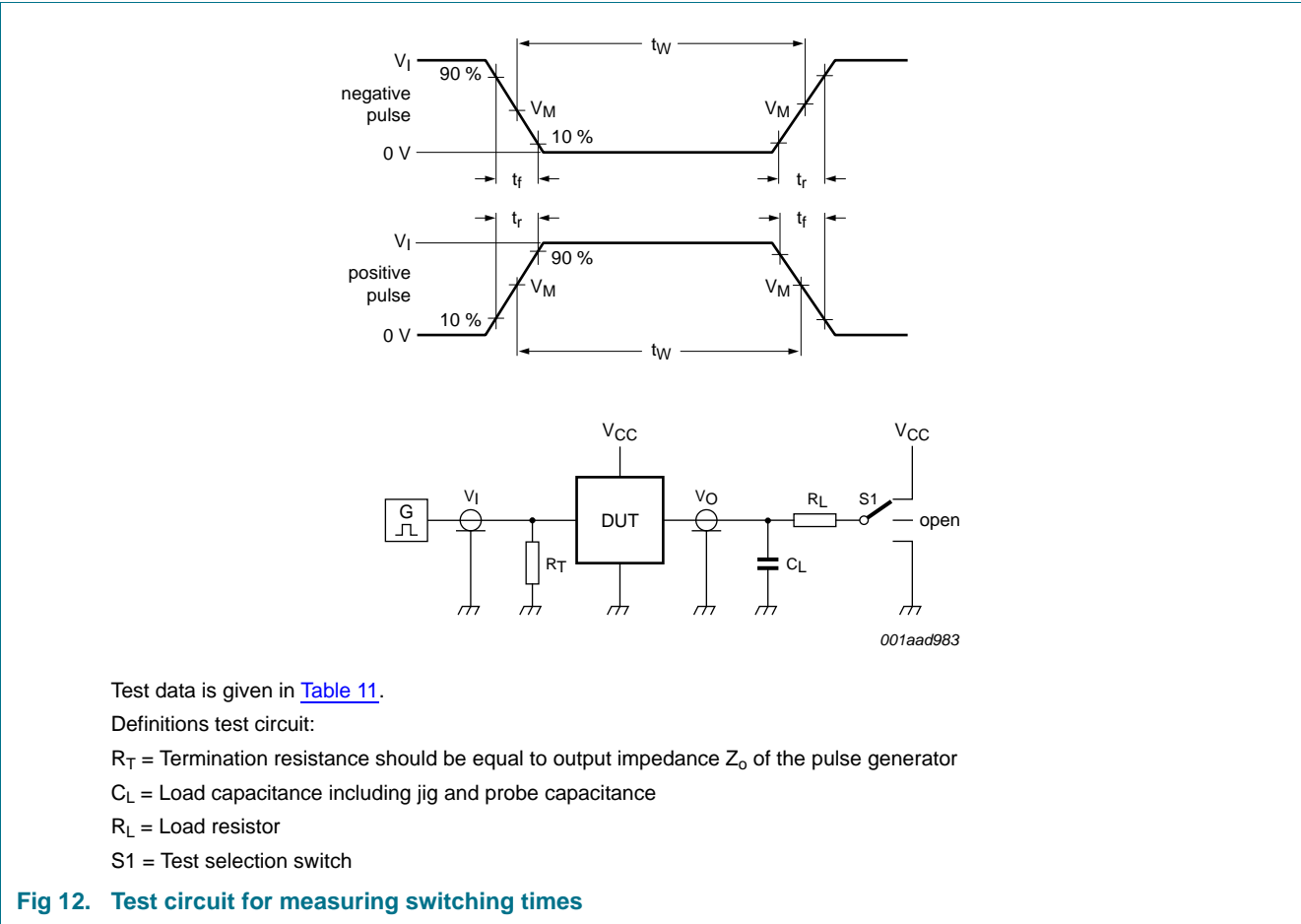


Fig 12. Test circuit for measuring switching times

Table 11. Test data

Type	Input		Load		S1 position		
	$V_I$	$t_r, t_f$	$C_L$	$R_L$	$t_{PHL}, t_{PLH}$	$t_{PZH}, t_{PHZ}$	$t_{PZL}, t_{PLZ}$
74HC373	$V_{CC}$	6 ns	15 pF, 50 pF	1 k $\Omega$	open	GND	$V_{CC}$
74HCT373	3 V	6 ns	15 pF, 50 pF	1 k $\Omega$	open	GND	$V_{CC}$



12. Package outline

DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1

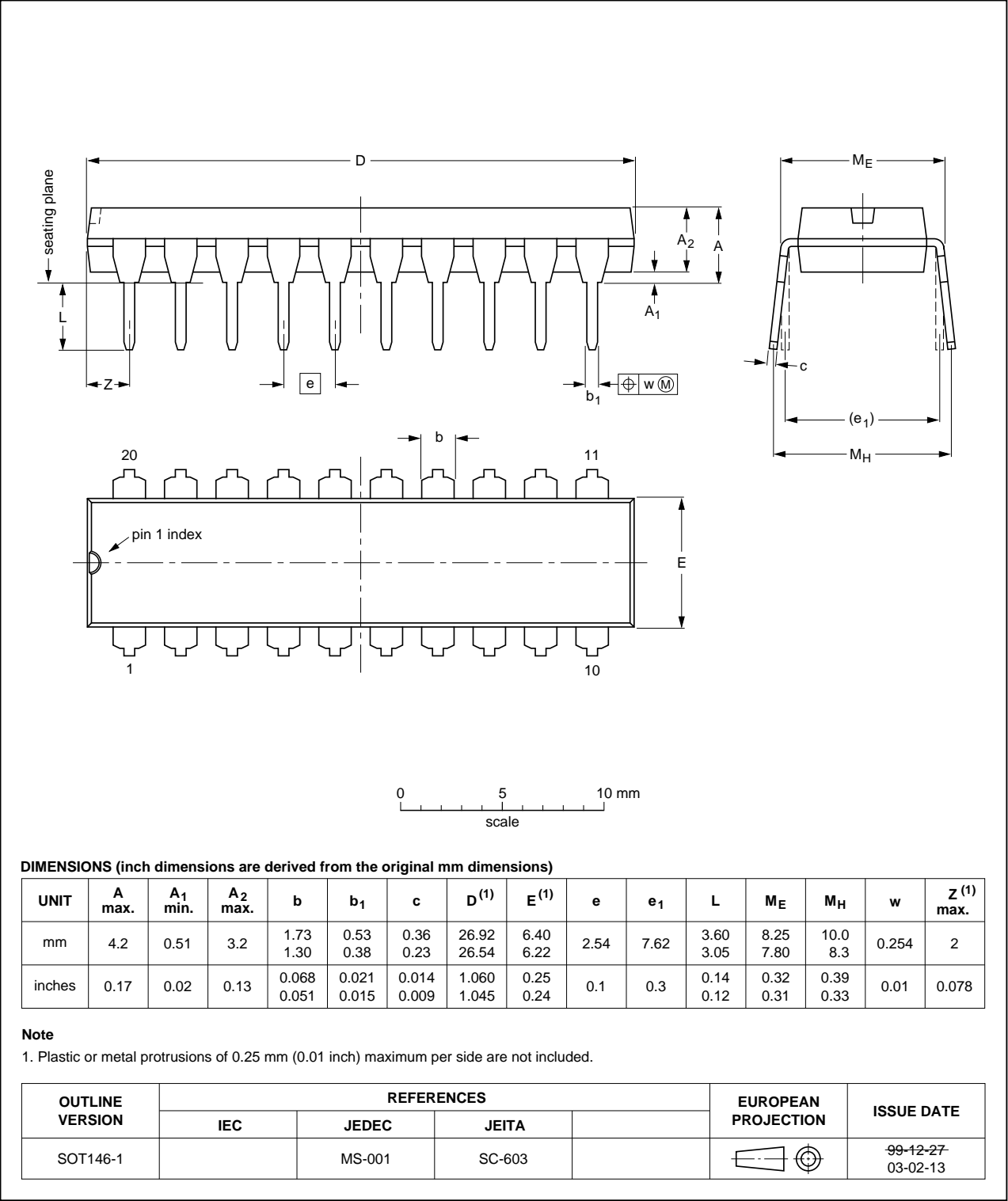


Fig 13. Package outline SOT146-1 (DIP20)

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1

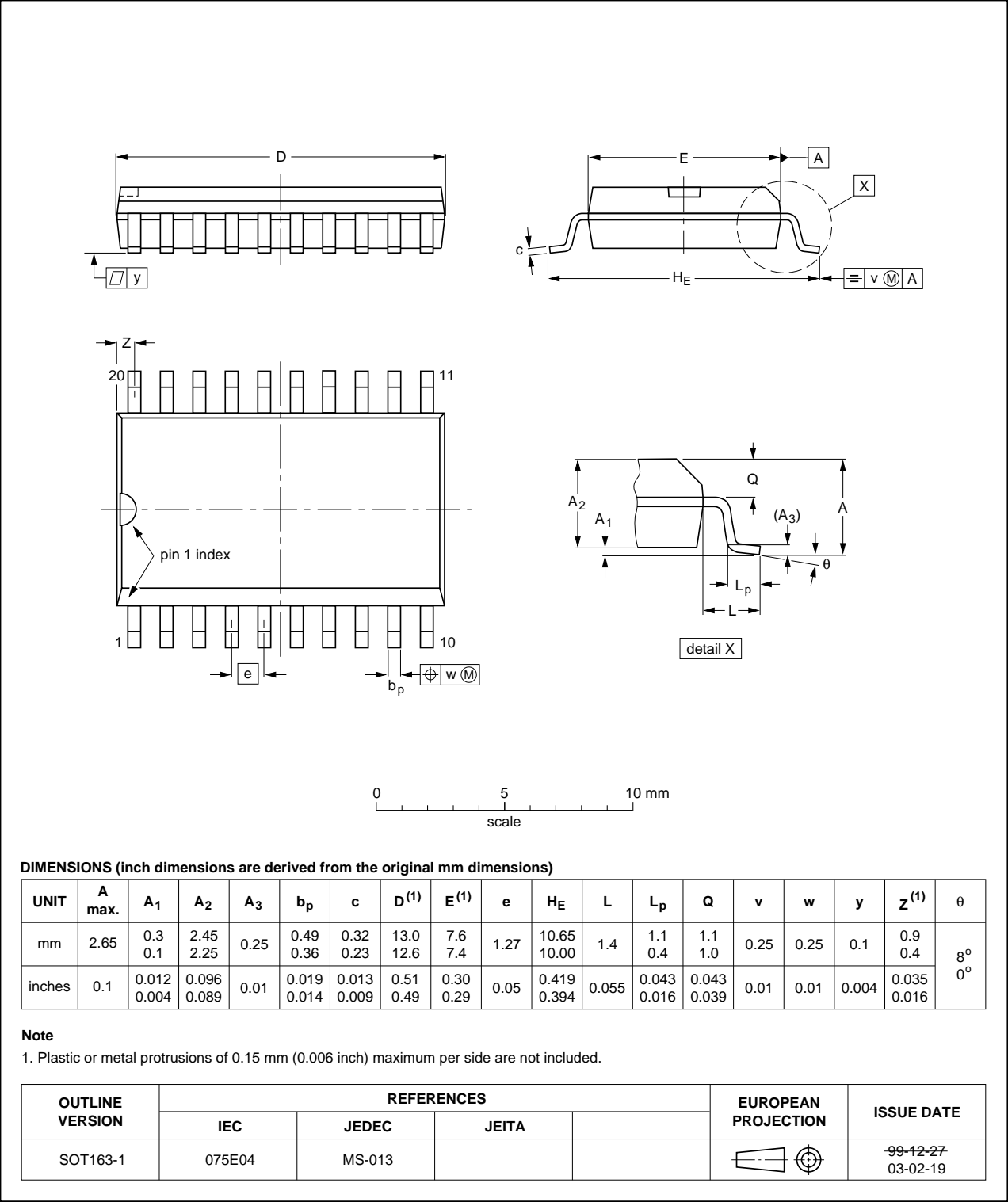


Fig 14. Package outline SOT163-1 (SO20)

SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1

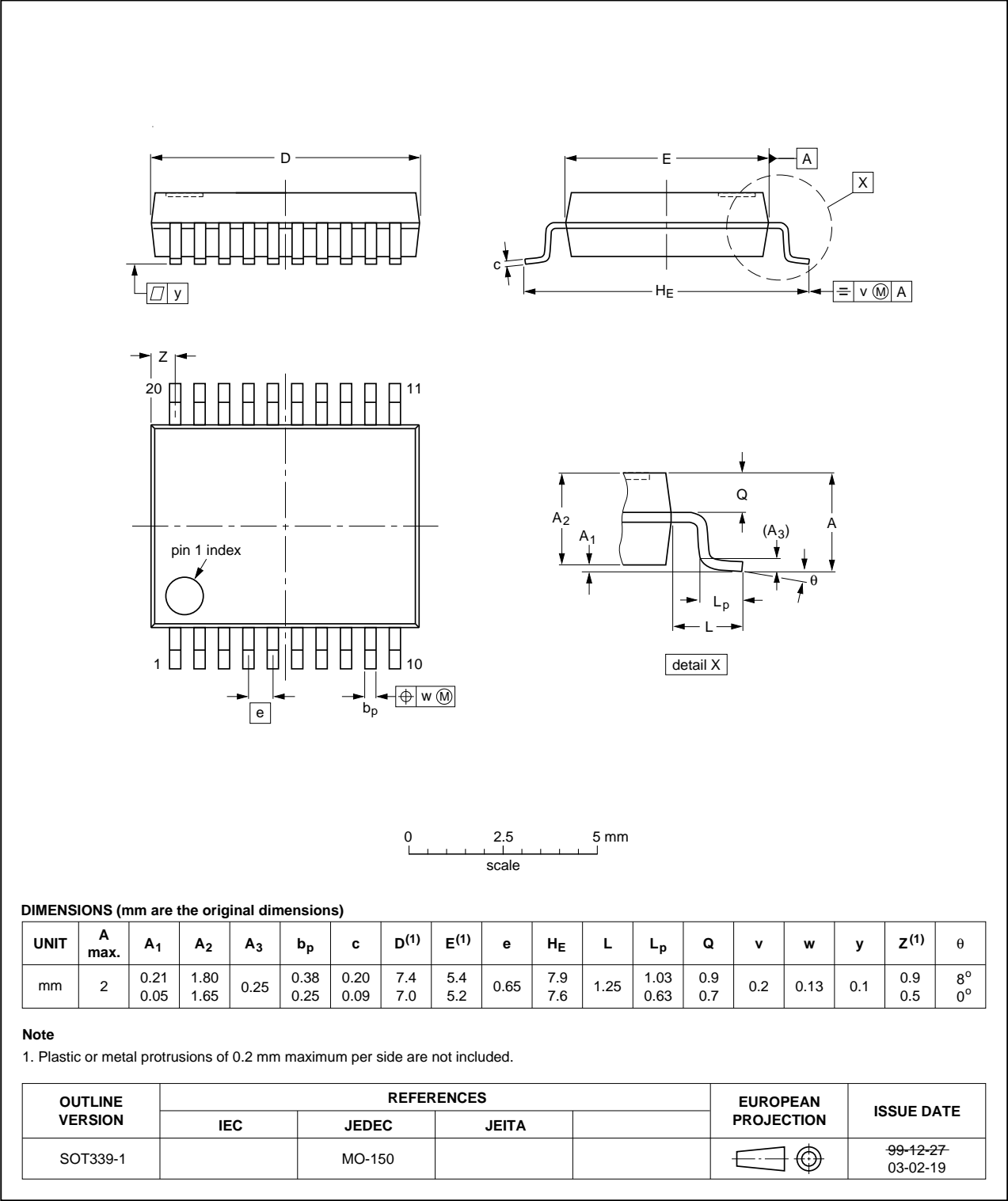


Fig 15. Package outline SOT339-1 (SSOP20)

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1

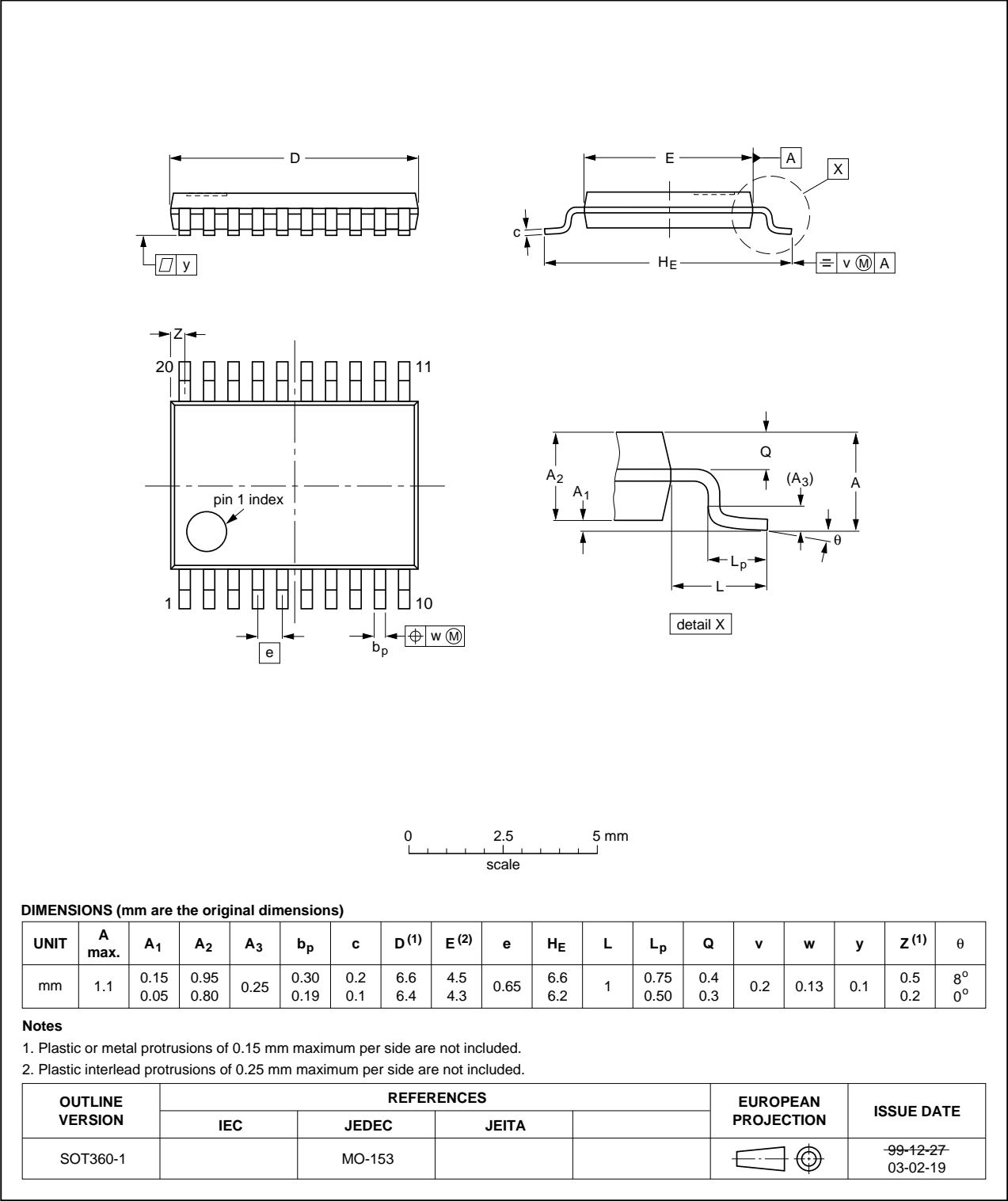
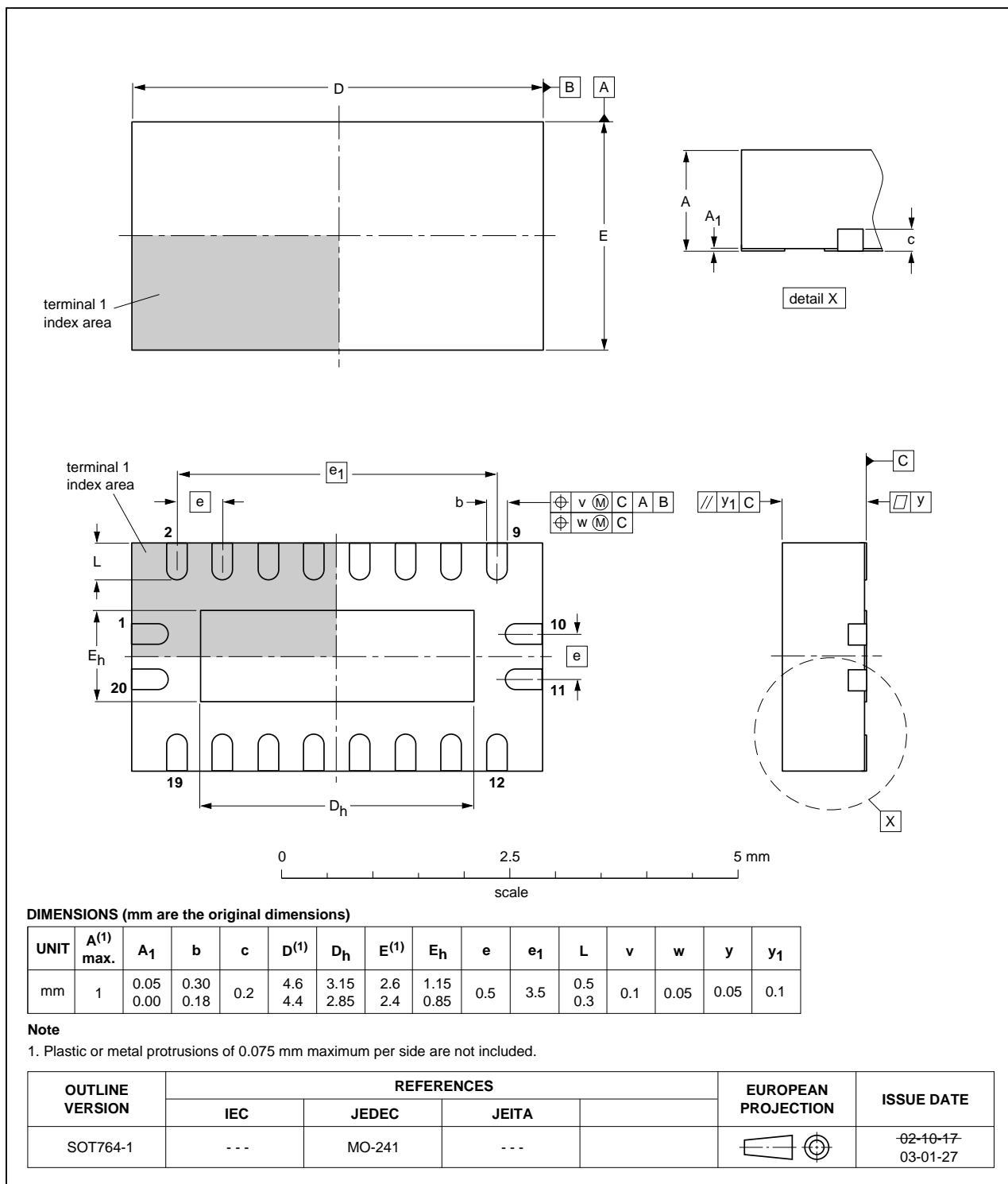


Fig 16. Package outline SOT360-1 (TSSOP20)

**DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm**

**SOT764-1**



**Fig 17. Package outline SOT764-1 (DHVQFN20)**

## 13. Abbreviations

Table 12. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

## 14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT373 v.5	20111213	Product data sheet	-	74HC_HCT373 v.4
Modifications:	• Legal pages updated.			
74HC_HCT373 v.4	20100903	Product data sheet	-	74HC_HCT373 v.3
74HC_HCT373 v.3	20060120	Product data sheet	-	74HC_HCT373_CNV v.2
74HC_HCT373_CNV v.2	19970827	Product specification	-	-

## 15. Legal information

### 15.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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